imall

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September 2000

IGBT

SGP15N60RUF

SGP15N60RUF Short Circuit Rated IGBT

General Description

Fairchild's Insulated Gate Bipolar Transistor(IGBT) RUF series provides low conduction and switching losses as well as short circuit ruggedness. RUF series is designed for the applications such as motor control, UPS and general inverters where short-circuit ruggedness is required.

Features

- Short Circuit rated 10us @ $T_C = 100^{\circ}C$, $V_{GE} = 15V$
- High Speed Switching
- Low Saturation Voltage : $V_{CE(sat)} = 2.2 \text{ V} @ I_C = 15 \text{ A}$
- High Input Impedance

Application

AC & DC Motor controls, General Purpose Inverters, Robotics, Servo Controls



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		SGP15N60RUF	Units
V _{CES}	Collector-Emitter Voltage		600	V
V _{GES}	Gate-Emitter Voltage		± 20	V
	Collector Current	@ T _C = 25°C	24	A
I _C	Collector Current	@ T _C = 100°C	15	Α
I _{CM (1)}	Pulsed Collector Current	-	45	Α
T _{SC} P _D	Short Circuit Withstand Time	@ T _C = 100°C	10	us
P _D	Maximum Power Dissipation	@ T _C = 25°C	160	W
	Maximum Power Dissipation	@ T _C = 100°C	64	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds		300	°C

Notes :

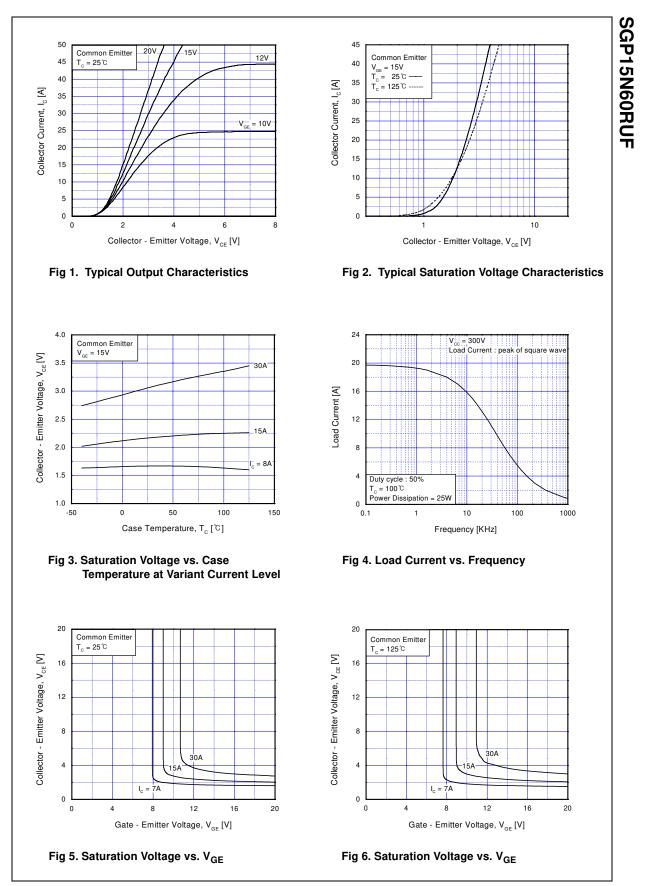
(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		0.77	°C/W
$R_{\theta JA}$	IA Thermal Resistance, Junction-to-Ambient		62.5	°C/W

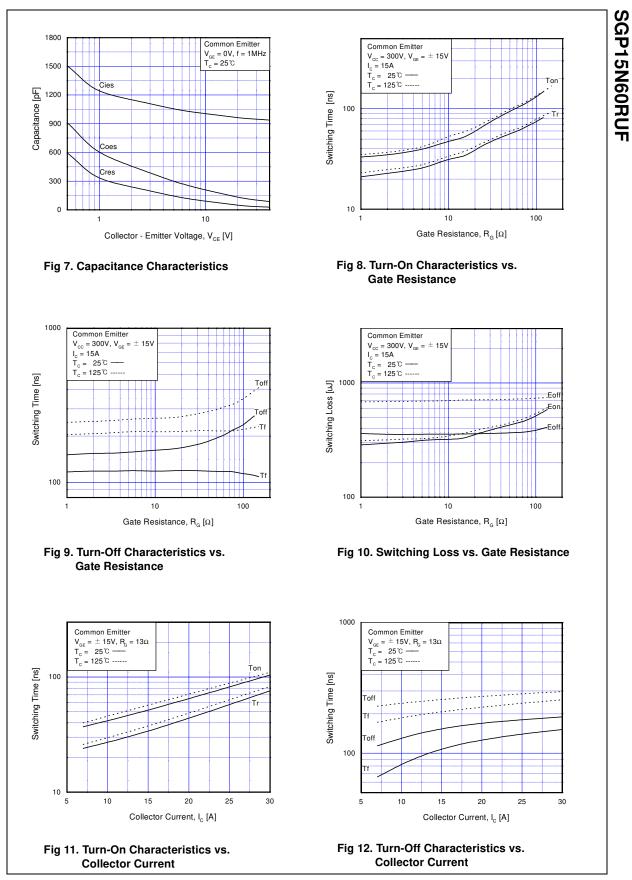
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} = 0V, I _C = 250uA	600			V
$\Delta B_{VCES}/$	Temperature Coeff. of Breakdown			0.0		N/100
ΔT_{J}	Voltage	$V_{GE} = 0V, I_C = 1mA$		0.6		V/°C
ICES	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			250	uA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
On Char	racteristics					
V _{GE(th)}	G-E Threshold Voltage	$I_{C} = 15 \text{mA}, V_{CE} = V_{GE}$	5.0	6.0	8.5	V
	Collector to Emitter	$I_{\rm C} = 15$ A, $V_{\rm GE} = 15$ V		2.2	2.8	V
V _{CE(sat)}	Saturation Voltage	$I_{\rm C} = 24 {\rm A}, V_{\rm GE} = 15 {\rm V}$		2.5		V
Dynami	c Characteristics					
C _{ies}	Input Capacitance			948		pF
C _{oes}	Output Capacitance	$V_{CE} = 30V$, $V_{GE} = 0V$,		101		pr pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz		33		pF
	ng Characteristics			4-	1	
t _{d(on)}	Turn-On Delay Time	_		17		ns
t _r	Rise Time			33		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, I_{C} = 15\text{A},$		44	65	ns
t _f	Fall Time	$R_{G} = 13\Omega, V_{GE} = 15V,$		118	200	ns
E _{on}	Turn-On Switching Loss	Inductive Load, $T_C = 25^{\circ}C$		320		uJ
E _{off}	Turn-Off Switching Loss	_		356		uJ
E _{ts}	Total Switching Loss			676	950	uJ
t _{d(on)}	Turn-On Delay Time	_		20		ns
t _r	Rise Time			34		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, \text{ I}_{C} = 15\text{ A},$		48	70	ns
t _f	Fall Time	$R_{G} = 13\Omega, V_{GE} = 15V,$		212	350	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C		340		uJ
E _{off}	Turn-Off Switching Loss	_		695		uJ
E _{ts}	Total Switching Loss	V300 V_V15V		1035	1450	uJ
T _{sc}	Short Circuit Withstand Time	$V_{CC} = 300 \text{ V}, V_{GE} = 15 \text{V}$ @ T _C = 100°C	10			us
Qg	Total Gate Charge	V _{CE} = 300 V, I _C = 15A,		42	60	nC
Q _{ge}	Gate-Emitter Charge	$-V_{GE} = 15V$		7	10	nC
Q _{gc}	Gate-Collector Charge			17	24	nC
Lp	Internal Emitter Inductance	Measured 5mm from PKG		7.5		nH

SGP15N60RUF



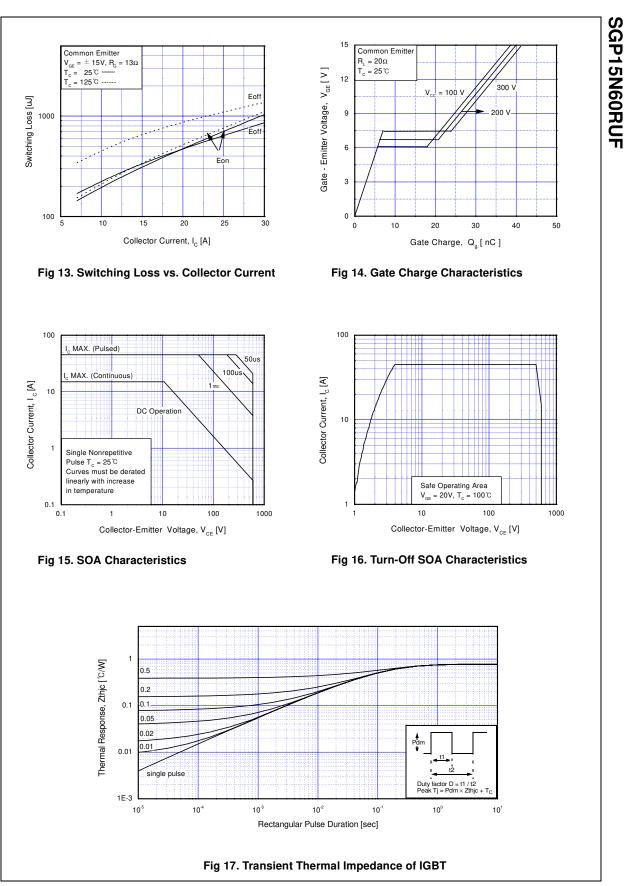
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